MGBR20L100C DIODE

# DUAL MOS GATED BARRIER RECTIFIER

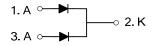
#### **■** DESCRIPTION

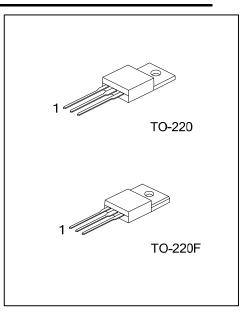
The UTC MGBR20L100C is a dual mos gated barrier rectifiers, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed, etc.

#### ■ FEATURES

- \* Low forward voltage drop
- \* High switching speed

# ■ SYMBOL

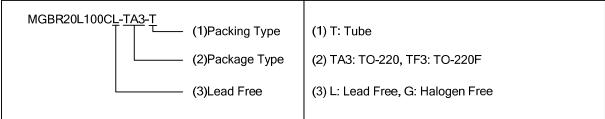




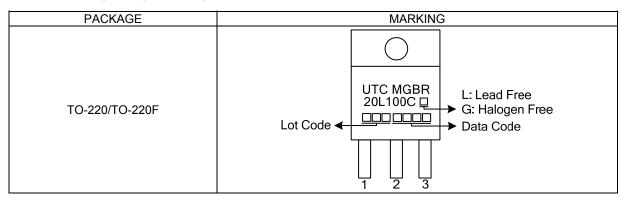
# **■ ORDERING INFORMATION**

Ordering Number		Dagkaga	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MGBR20L100CL-TA3-T	MGBR20L100CG-TA3-T	TO-220	Α	K	Α	Tube	
MGBR20L100CL-TF3-T	MGBR20L100CG-TF3-T	TO-220F	Α	K	Α	Tube	

Note: Pin Assignment: A: Anode, K: Cathode



#### ■ MARKING INFORMATION



www.unisonic.com.tw 1 of 3

MGBR20L100C DIODE

# ■ ABSOLUTE MAXIMUM RATINGS (PER LEG) (T<sub>A</sub>=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER		SYMBOL	RATINGS	UNIT
DC Blocking Voltage		$V_{RM}$	100	V
Working Peak Reverse Voltage		$V_{RWM}$	100	V
Peak Repetitive Reverse Voltage		$V_{RRM}$	100	V
Average Destified Output Comment Day Device	Per Leg		10	Α
Average Rectified Output Current Per Device	Total	Io	20	Α
Non-Repetitive Peak Forward Surge Current 8 Half Sine-Wave Superimposed on Rated Load	•	I <sub>FSM</sub>	150	Α
Operating Junction Temperature		$T_J$	-65~+150	°C
Storage Temperature		$T_{STG}$	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### ■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient		$\theta_{JA}$	62.5	°C/W
lungtion to Occa-	TO-220	0	2	°C/M/
Junction to Case	TO-220F	$\theta_{JC}$	3.31	°C/W

# ■ ELECTRICAL CHARACTERISTICS (PER LEG) (T<sub>A</sub> =25°C unless otherwise specified.)

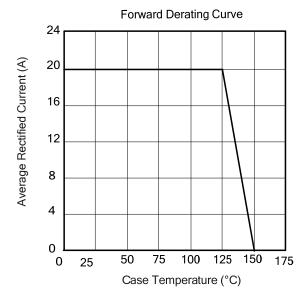
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	I <sub>R</sub> =0.50mA	100			V
Forward Voltage Drop	$V_{FM}$	I <sub>F</sub> =10A, T <sub>J</sub> =25°C			0.80	V
		I <sub>F</sub> =10A, T <sub>J</sub> =125°C			0.75	V
Leakage Current (Note 1)	lьм	V <sub>R</sub> =100V, T <sub>J</sub> =25°C			100	μA
		V <sub>R</sub> =100V, T <sub>J</sub> =125°C			10	mA

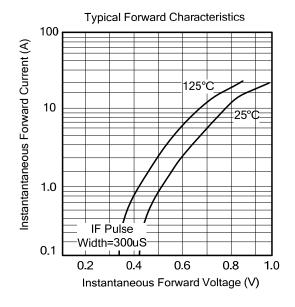
Notes: 1. Short duration pulse test used to minimize self-heating effect.

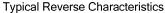
<sup>2.</sup> Thermal resistance junction to case mounted on heatsink.

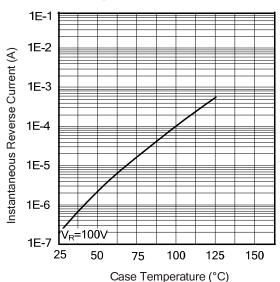
MGBR20L100C DIODE

# **■ TYPICAL CHARACTERISTICS**









UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.